# Wire bonding Vertical Silicon Capacitor WBSC / WLSC 0402



#### Rev.2.05

# General description

WBSC / WLSC Capacitors target power supplies decoupling and filtering of active devices. They are based on PICS Integrated Passive technology.

This product is a single 22nF capacitor in 0402 package size (1.00 x 0.50 mm). Other capacitance values and other package size are available as a single die or capacitor array; please feel free to contact us.

WBSC/WLSC capacitors are directly mounted on the PCB application using die bonding and wire bonding processes. Standard FR4 PCB can be used. The bottom electrode is in TiNiAu and the top electrode is in TiWAu. Other top finishings such as Aluminum are available on request.

#### Key features

- o Full compatible Monolithic ceramic capacitors for replacement
- Ultra-high stability of capacitance value:
- Temperature 70ppm/K (-55 °C to +150 °C)
- Voltage < -0.02%/Volt
- Negligible capacitance loss through ageing
- Low profile 0.25mm (standard), but lower thickness is possible (i.e 0.10mm) on request
- Small size 1.00 x 0.50 mm (0402 format)

- Break down voltage: 30V
- Low leakage current
- High reliability
- High operating temperature (up to 150 °C)
- Compatible with high temperature cycling during manufacturing operations (exceeding 300 °C)
- Compatible with EIA 0402 footprint
- Applicable for standard wire bonding assembly (ball and wedge)

#### Key applications

- Any demanding applications, such as medical, aerospace, automotive industrial...
- Supply decoupling / filtering of active device
- High reliability applications
- High temperature applications
- High volumetric efficiency (i.e. capacitance per unit volume)





## Functional diagram

The next figure provides implementation set-up diagram.



Figure 1 Block Diagram

## Electrical performances

| Symbol            | Parameter                         | Conditions                             | Min. | Тур. | Max.                                       | Unit              |
|-------------------|-----------------------------------|----------------------------------------|------|------|--------------------------------------------|-------------------|
| С                 | Capacitance value                 | @+25°C                                 |      | 22   | -                                          | nF                |
| $\Delta C_P$      | Capacitance tolerance (1)         | @+25°C                                 | -15  |      | +15                                        | %                 |
| T <sub>OP</sub>   | Operating temperature             |                                        | -55  | 20   | 150                                        | °C                |
| T <sub>STG</sub>  | Storage temperature (2)           |                                        | -70  | -    | 165                                        | °C                |
| $\Delta C_T$      | Capacitance temperature variation | -55°C to 150°C                         |      | 70   |                                            | ppm/K             |
| RV <sub>DC</sub>  | Rated voltage (3)                 |                                        | -    |      | 16.0 <sup>(4)</sup><br>14.7 <sup>(5)</sup> | V <sub>DC</sub>   |
| BV                | Breakdown voltage                 | @+25°C                                 | 30   | -    | -                                          | $V_{DC}$          |
| $\Delta C_{RVDC}$ | DC Capacitance voltage variation  | From 0V to RV <sub>DC</sub> ,<br>@25°C | -    | -    | -0.02                                      | %/V <sub>DC</sub> |
| IR                | Insulation resistance             | @ RV <sub>DC</sub> , +25°C, 120s       | -    | 10   | -                                          | GΩ                |
| ESL               | Equivalent Series Inductance      | @+25°C, SRF shunt mode                 | -    | 3    | -                                          | рН                |
| ESD               | HBM stress (6)                    | JS-001-2017                            | 2    | -    | -                                          | kV                |

Table 1 - Electrical performances

- (1): other tolerance available upon request
- (2): without packaging
- (3): Lifetime is voltage and temperature dependent, please refer to application note 'Lifetime of 3D capacitors'
- (4): 10 years of intrinsic life time prediction at 100°C continuous operation
- (5): 10 years of intrinsic life time prediction at 150°C continuous operation
- (6): please refer to application note 'ESD Challenge in 3D Murata Integrated Passive technology'

For extended frequency range (up to 26GHz), see Ultra large band Wire bonding vertical Silicon Capacitor (UWSC).





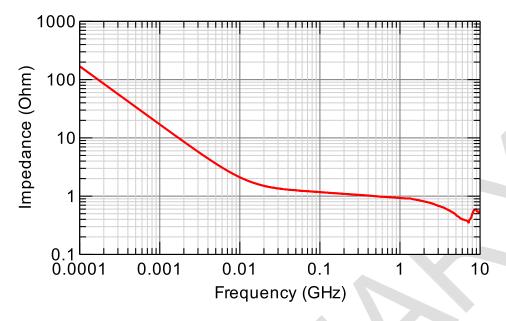


Figure 2 Impedance characteristic versus Frequency in shunt mode

# Schematic of 22nF WBSC in Shunt mode

# WBSC837.522 50Ω 50Ω

Figure 3 - 22nF WBSC measurement schematic

# **Example of mounted 0202**

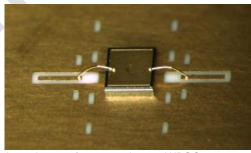


Figure 4 - micro picture of mounted 0202 WBSC



# Pinning definition

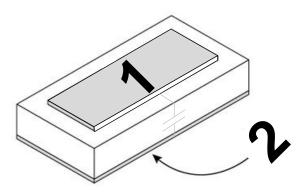


Figure 5 Pinning definition

| pin # | Symbol | Coordinates X / Y |  |  |  |  |
|-------|--------|-------------------|--|--|--|--|
| 1     | Signal | 0.0 / 0.0         |  |  |  |  |
| 2     | GND    | Backside          |  |  |  |  |

Table 2 - Pining description. Reference (0,0) located at the centre of the die.

# **Ordering Information**

Murata Integrated Passive Devices delivers products with AQL level II (0.65). Tighter quality levels are available upon request.

| Dout number      |                             | :kage             | Die Name                              |               |  |
|------------------|-----------------------------|-------------------|---------------------------------------|---------------|--|
| Part number      | Packaging                   | Finishing         | Description                           | Die Name      |  |
| 935142837522-F1T | 6" FFC <sup>(1)</sup>       | Au <sup>(2)</sup> | <b>)</b>                              |               |  |
| 935142837522-F2T | 8" FFC <sup>(1)</sup>       | Au <sup>(2)</sup> |                                       |               |  |
| 935142837522-E1T | 6" Grip Ring <sup>(1)</sup> | Au <sup>(2)</sup> | WBSC 22nF/0402/BV30<br>1 bondpad      | WR0402522     |  |
| 935142837522-T3T | T&R 1Kunits <sup>(4)</sup>  | Au <sup>(2)</sup> | 1.00 x 0.50mm x 0.25mm <sup>(3)</sup> |               |  |
| 935142837522-W0T | Waffle pack                 | Au <sup>(2)</sup> |                                       |               |  |
| 935146837522-F1T | 6" FFC <sup>(1)</sup>       | Au <sup>(2)</sup> |                                       |               |  |
| 935146837522-F2T | 8" FFC <sup>(1)</sup>       | Au <sup>(2)</sup> |                                       | WR0402522     |  |
| 935146837522-E1T | 6" Grip Ring <sup>(1)</sup> | Au <sup>(2)</sup> | WLSC 22nF/0402/BV30<br>1 bondpad      | VVI (0 102022 |  |
| 935146837522-T3T | T&R 1Kunits(4)              | Au <sup>(2)</sup> | 1.00 x 0.50mm x 0.10mm <sup>(3)</sup> |               |  |
| 935146837522-W0T | Waffle pack<br>400units     | Au <sup>(2)</sup> |                                       |               |  |

Table 3 - Packaging and ordering information

<sup>(1)</sup> Other film frame carrier are possible on request

<sup>(2)</sup> Au= TiWAu (0.3μm) / Au (3μm) (3) Refer to Package outline (4) missing capacitors can reach 0.5%



#### Pad Metallization

The wire bondable capacitor like WBSC / WLSC is delivered as standard with the bottom electrode in TiNiAu ( $_{\text{Ti=0.1}\mu\text{m; Ni=0.3}\mu\text{m; Au=0.2}\mu\text{m}}$ ) and top electrode in TiWAu (0.3 $\mu$ m) / Au (3 $\mu$ m).

Other Metallization, such as Thick Gold or Aluminum pads are possible on request.

Silicon dies are not sensitive to humidity, please refer to applications notes 'Assembly Notes' section 'Handling precautions and storage'.

## Material regulation

This product is RoHS compliant at the time of publication. For further information about regulation compliancy, please ask your sales representative.

# Package outline

The product is delivered as a bare silicon die.

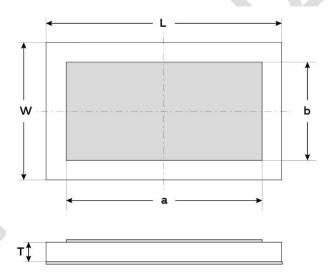


Figure 6 - Package outline drawing

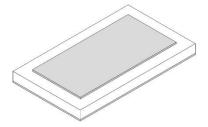


Figure 7 - Package isometric view



| L (mm)                | W (mm)                | (mm) T (mm)  |       | b (mm) |  |
|-----------------------|-----------------------|--------------|-------|--------|--|
| 1.00 <sub>±0.03</sub> | 0.50 <sub>±0.03</sub> | 0.25 or 0.10 | 0.818 | 0.318  |  |
| 1.00 ±0.03            |                       | ±0.015       | 0.010 | 0.510  |  |

Table 4 - Dimensions and tolerances

## Assembly

The attachment techniques recommended by Murata on the customer's substrates are fully detailed in specific documents available on our website. To assure the correct use and proper functioning of Murata capacitors please download the assembly instructions on <a href="https://www.murata.com/en-us/products/capacitor/siliconcapacitors">https://www.murata.com/en-us/products/capacitor/siliconcapacitors</a> and read them carefully.



Figure 8 Scan this QR Code to access the Murata Silicon Capacitor web page

# Packaging format

Please refer to application note 'Products Storage Conditions and Shelf Life'.

# Tape and Reel:

Dies are flipped in the tape cavity (bump down) with die ID located near the driving holes of the tape.

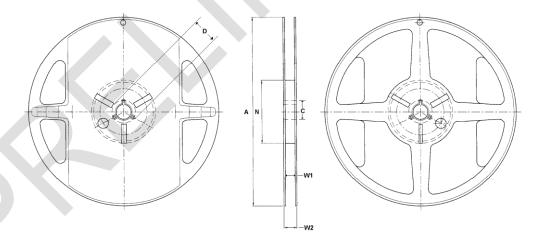


Figure 9 - Reel drawing



| Tape<br>Width | Diameter<br>A     | С    | D    | Hub<br>N | <b>W</b> 1 | W2   |
|---------------|-------------------|------|------|----------|------------|------|
| 8             | 178<br>(7 inches) | 13.5 | 20.2 | 60       | 9.3        | 11.5 |

Table 5 – Reel dimensions (mm)

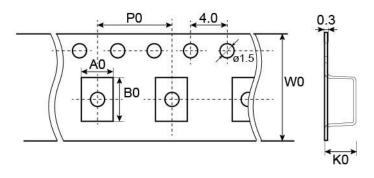


Figure 10 - Tape drawing

| Cavity dimensions |      |      | Carrier tape | Carrier tape | Reel     |  |
|-------------------|------|------|--------------|--------------|----------|--|
| Ao                | Во   | Ко   | width W0     | pitch P0     | Capacity |  |
| 0.59              | 1.09 | 0.20 | 8            | 4            | 1000     |  |
| 0.65              | 1.14 | 0.33 | 8            | 4            | 1000     |  |

Table 6 - Tape dimensions (mm)

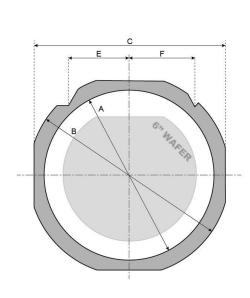




## Film frame carrier:

With UV curable dicing tape (UV performed).

Good dies are identified using the SINF electronic mapping format. No ink is added on wafer to label other dies.



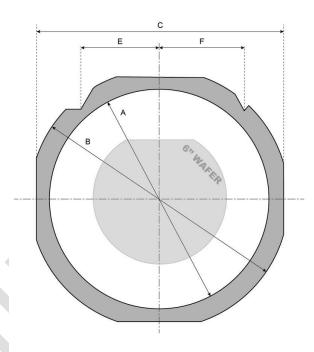


Figure 11 FF070 Frame with a 6" wafer

Figure 12 FF108 Frame with a 6" wafer

| Frame<br>Reference   | Frame<br>Style | Inside<br>diameter<br>A | Outside<br>diameter<br>B | Width<br>C | Thickness | Pin<br>location<br>E | Pin<br>location<br>F |
|----------------------|----------------|-------------------------|--------------------------|------------|-----------|----------------------|----------------------|
| FF070 <sup>(1)</sup> | DTF-2-6-1      | 7.638"                  | 8.976"                   | 8.346"     | 0.048"    | 2.370"               | 2.5"                 |
| FF108 <sup>(1)</sup> | DTF-2-8-1      | 9.842"                  | 11.653"                  | 10.866"    | 0.048"    | 2.381"               | 2.5"                 |

Table 7 - Frame dimensions (inches)

(1) or equivalent



# Waffle pack:

Please refer to application note 'Waffle Pack Chip Carrier Handling & Opening Procedure'. Dies are not flipped in the waffle pack cavity (wire bond pad up).

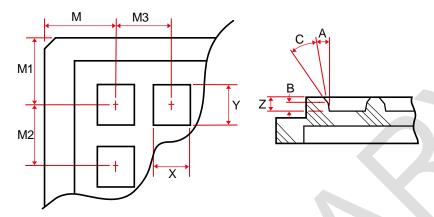


Table 8 - Waffle pack drawing

| Supplier reference | External dimensions | Max. capacity | Pocket<br>length X | Pocket width Y | Pocket<br>depth Z |
|--------------------|---------------------|---------------|--------------------|----------------|-------------------|
| (*)                | 2 inches            | 20 x 20       | tbd                | tbd            | tbd               |

Table 9 - Waffle pack dimensions (mm) for 250µm thick product

(\*) or equivalent

| M   | M1  | M2  | М3  | Α   |
|-----|-----|-----|-----|-----|
| tbd | tbd | tbd | tbd | tbd |

Table 10 - Waffle pack dimensions (mm) for 250µm thick product

| Supplier reference | External dimensions | Max. capacity | Pocket<br>length X | Pocket width Y | Pocket<br>depth Z |
|--------------------|---------------------|---------------|--------------------|----------------|-------------------|
| (*)                | 2 inches            | 20 x 20       | tbd                | tbd            | tbd               |

Table 11 Waffle pack dimensions (mm) for 100µm thick product

| M   | M1  | M2  | М3  | Α   |
|-----|-----|-----|-----|-----|
| tbd | tbd | tbd | tbd | tbd |

Table 12: Waffle pack dimensions (mm) for 100µm thick product



# **Expander Grip Ring 6" diameter:**

With UV curable dicing tape (UV performed)

Good dies are identified using the SINF electronic mapping format.

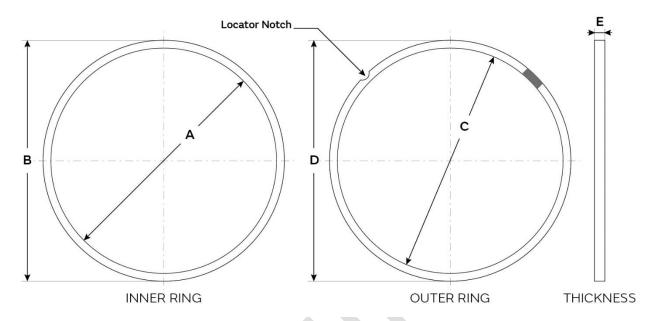


Figure 13 – Grip Ring drawing

| Grip Ring<br>Style        | А      | В      | С      | D      | Е      | Locator<br>Notch |
|---------------------------|--------|--------|--------|--------|--------|------------------|
| GRP-2620-6 <sup>(*)</sup> | 7.670" | 7.973" | 7.975" | 8.280" | 0.236" | None             |

Table 13 - Frame dimensions (inches)

(\*) or equivalent







#### **Definitions**

#### Data sheet status

Objective specification: This data sheet contains target or goal specifications for product development.

**Preliminary specification:** This data sheet contains preliminary data; supplementary data may be published later.

**Product specification:** This data sheet contains final product specifications.

#### Limiting values

Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those given in the Electrical performances sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

#### **Revision history**

| Revision | Date                       | Description               | Author |
|----------|----------------------------|---------------------------|--------|
| Rev 1.00 | 2010 August 13th           | Creation                  | OGA    |
| Rev 2.04 | 2020 Sept. 7th             | General update            | OGA    |
| Rev.2.05 | 2021 Feb. 24 <sup>th</sup> | Layout and content update | CG/OGA |

#### Disclaimer / Life support applications

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Murata customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Murata for any damages resulting from such improper use or sale.

Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

Murata Integrated Passive Solutions S.A. makes no representation that the use of its products in the circuits described herein, or the use of other technical information contained herein, will not infringe upon existing or future patent rights. The descriptions contained herein do not imply the granting of licenses to make, use, or sell equipment constructed in accordance therewith. Specifications are subject to change without notice.



